

HAT2068R

Silicon N Channel Power MOS FET **Power Switching**

R07DS0871EJ0600

(Previous: REJ03G1176-0500)

Rev.6.00

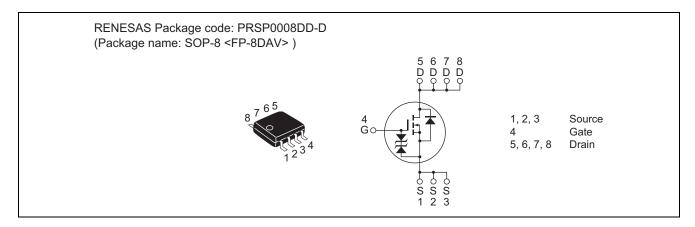
Aug 23, 2012

Features

- Capable of 4.5 V gate drive
- Low drive current
- High density mounting
- Low on-resistance

 $R_{DS\;(on)}$ = 7 mW typ. (at V_{GS} = 10 V)

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Value	Unit
Drain to source voltage	V _{DSS}	30	V
Gate to source voltage	V _{GSS}	±20	V
Drain current	I _D	14	А
Drain peak current	I _{D (pulse)} Note 1	112	А
Body-drain diode reverse drain current	I _{DR}	14	А
Channel dissipation	Pch Note 2	2.5	W
Channel to ambient thermal impedance	θ ch-a Note 2	50	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. When using the glass epoxy board (FR4 $40 \times 40 \times 1.6$ mm), PW \leq 10 s

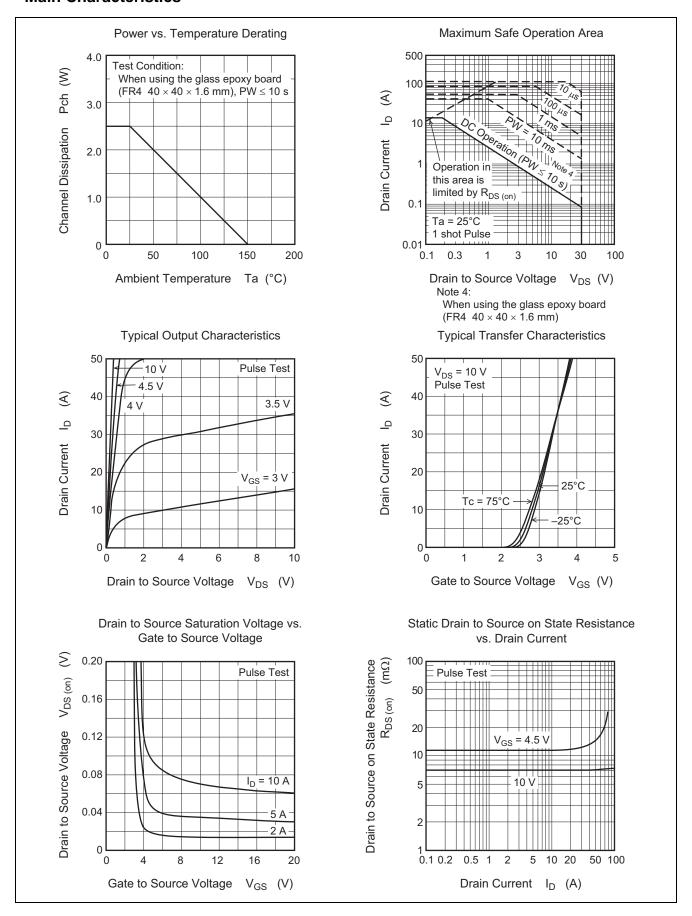
Electrical Characteristics

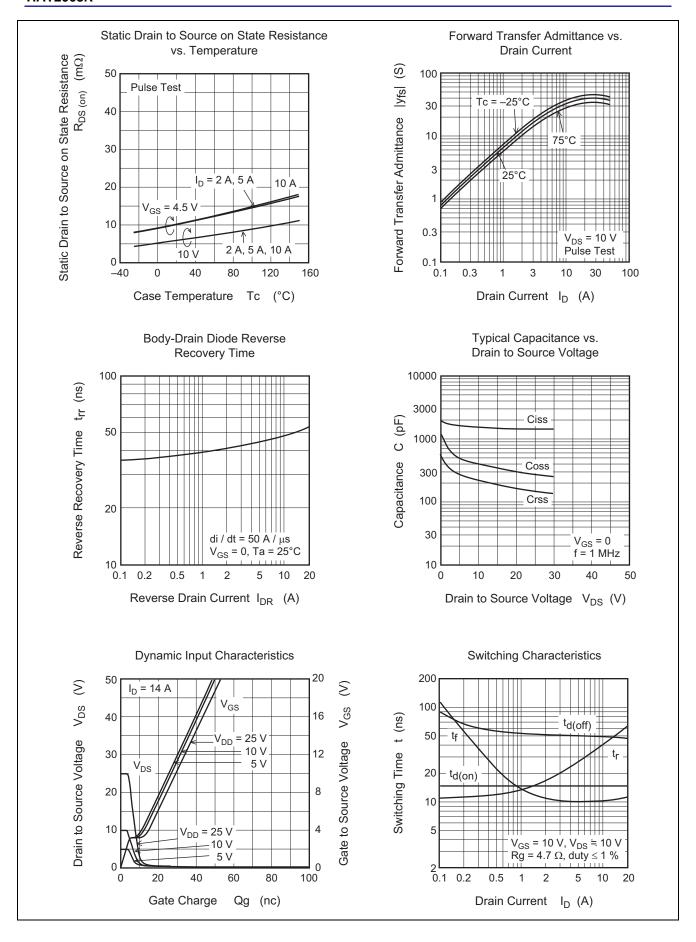
 $(Ta = 25^{\circ}C)$

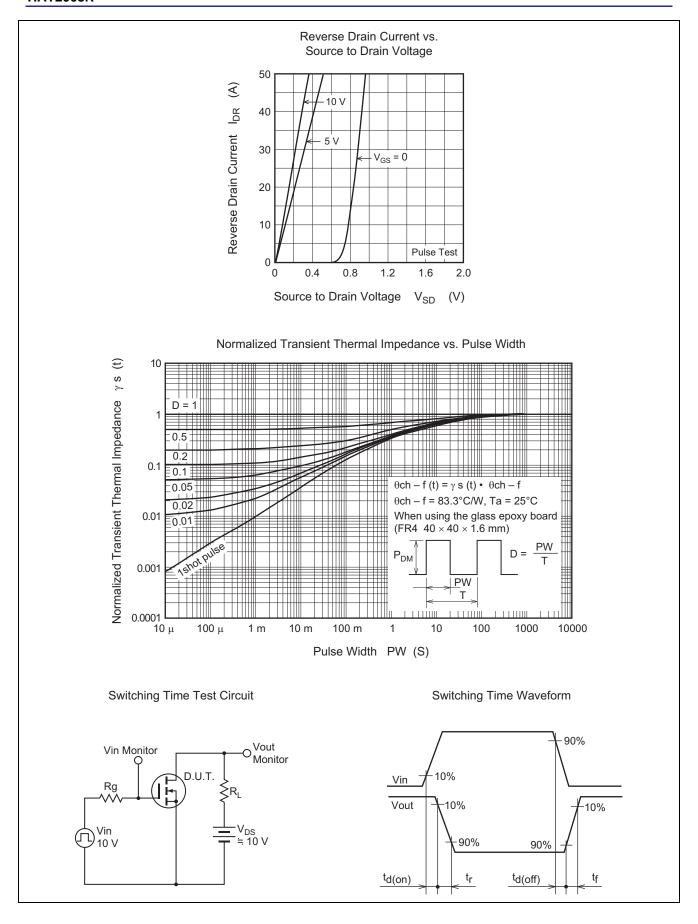
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V _{(BR) DSS}	30	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	V _{(BR) GSS}	±20	_	_	V	$I_G = \pm 100 \ \mu A, \ V_{DS} = 0$
Gate to source leak current	I _{GSS}	_	_	±10	μΑ	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	1	μΑ	$V_{DS} = 30 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	V _{GS (off)}	1.0	_	2.5	V	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$
Static drain to source on state resistance	R _{DS (on)}	_	7	9	mΩ	$I_D = 7 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note 3}}$
	R _{DS (on)}	_	11	16	mΩ	$I_D = 7 \text{ A}, V_{GS} = 4.5 \text{ V}^{\text{Note 3}}$
Forward transfer admittance	y _{fs}	16	28	_	S	$I_D = 7 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note 3}}$
Input capacitance	Ciss	_	1650	_	pF	V _{DS} = 10 V
Output capacitance	Coss	_	400	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	_	220	_	pF	f = 1 MHz
Total gate charge	Qg	_	26	_	nC	V _{DD} = 10 V
Gate to source charge	Qgs	_	5	_	nC	V _{GS} = 10 V
Gate to drain charge	Qgd	_	5	_	nC	I _D = 14 A
Turn-on delay time	t _{d (on)}	_	15	_	ns	$V_{GS} = 10 \text{ V}, I_D = 7 \text{ A}$
Rise time	t _r	_	30	_	ns	$V_{DD} \approx 10 \text{ V}$
Turn-off delay time	t _{d (off)}	_	50	_	ns	$R_L = 1.43 \Omega$
Fall time	t _f	_	10	_	ns	$Rg = 4.7 \Omega$
Body-drain diode forward voltage	V_{DF}	_	0.80	1.04	V	$I_F = 14 \text{ A}, V_{GS} = 0^{\text{Note 3}}$
Body-drain diode reverse recovery time	t _{rr}	_	50	_	ns	$I_F = 14 \text{ A}, V_{GS} = 0$ $di_F/dt = 50 \text{ A}/\mu\text{s}$

Note: 3. Pulse test

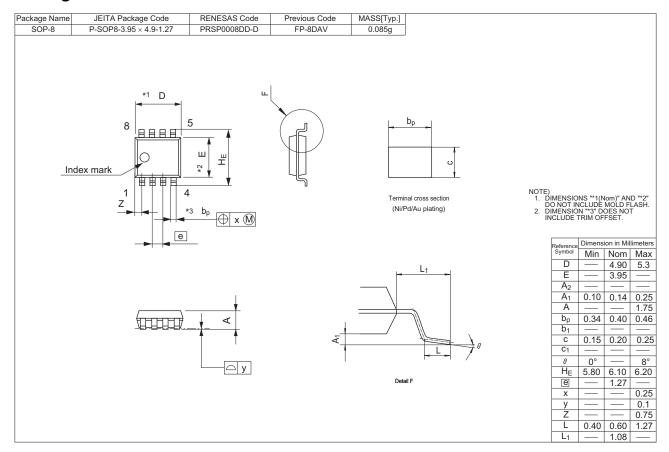
Main Characteristics







Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
HAT2068R-EL-E	2500 pcs	Taping

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